

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier with sensitive gate in a TO92 plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic ICs and other low power gate trigger circuits.

2. Features and benefits

- · Planar passivated for voltage ruggedness and reliability
- Sensitive gate
- Direct triggering from low power gate circuits and logic ICs

3. Applications

- Ignition circuits
- Lighting ballasts
- Protection circuits
- Switched Mode Power Supplies

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Absolute	maximum rating	· · · · · · · · · · · · · · · · · · ·	· · ·				
V_{RRM}	repetitive peak reverse voltage			-	-	200	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>		-	-	0.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	-	0.8	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5		-	-	8	А
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms		-	-	9	А
Tj	junction temperature			-	-	125	°C
Static cha	aracteristics	· · · · ·					
I _{GT}	gate trigger current	$V_{\rm D}$ = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>		-	50	200	μA
Dynamic	characteristics	· · · · ·					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 134 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 12		500	800	-	V/µs
		V_{DM} = 134 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12		-	25	-	V/µs

5. Pinning information

Table 2. F	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	А	anode		
2	G	gate	L. L.	а Ц к
3	К	cathode	0 0 0 0 0 0 3 2 1 TO-92 (SOT54)	G sym037

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
BT169B	TO92	BT169B,126	Reel	2000	SOT54 wide pitch	14-Nov-2013		

7. Marking

Table 4. Marking codes							
	Type number	Marking codes					
	BT169B	BT169B					

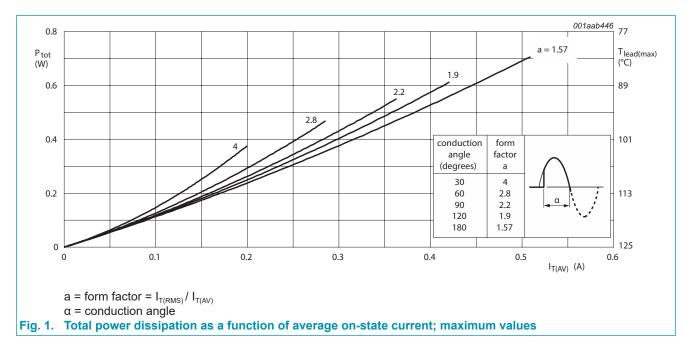
8. Limiting values

Table 5. Limiting values

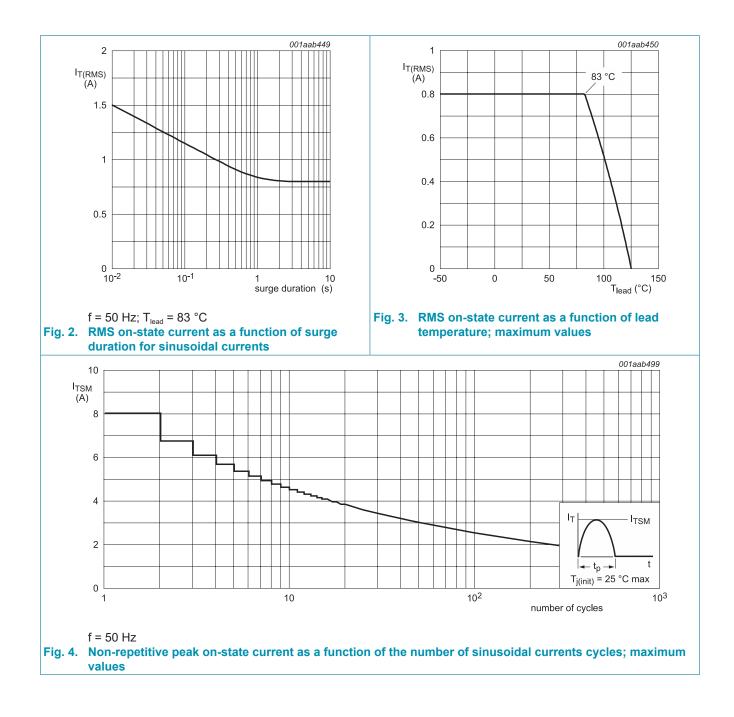
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage			-	200	V
V _{RRM}	repetitive peak reverse voltage			-	200	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>		-	0.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>		-	0.8	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5		-	8	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms		-	9	А
l ² t	l ² t for fusing	t _p = 10 ms; SIN		-	0.32	A ² s
dl _⊤ /dt	rate of rise of on-state current	$I_T = 2 \text{ A}; I_G = 10 \text{ mA}; \text{dI}_G/\text{dt} = 100 \text{ mA}/\mu\text{s}$		-	50	A/µs
I _{GM}	peak gate current			-	1	А
V_{RGM}	peak reverse gate voltage			-	5	V
P _{GM}	peak gate power			-	2	W
P _{G(AV)}	average gate power	over any 20 ms period		-	0.1	W
T _{stg}	storage temperature			-40	150	°C
Tj	junction temperature		[1]	-	125	°C

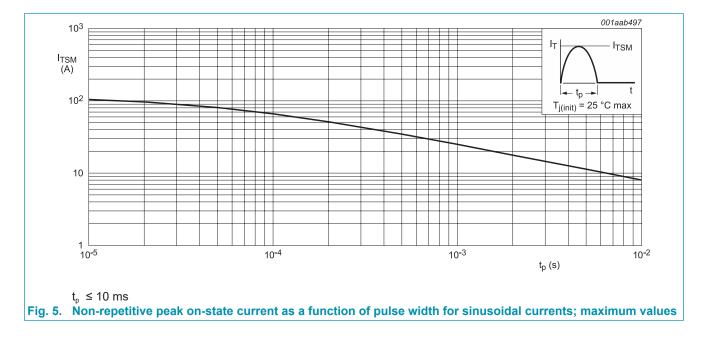
[1] Operation above 110°C may require the use of a gate to cathode resistor of $1k\Omega$ or less.



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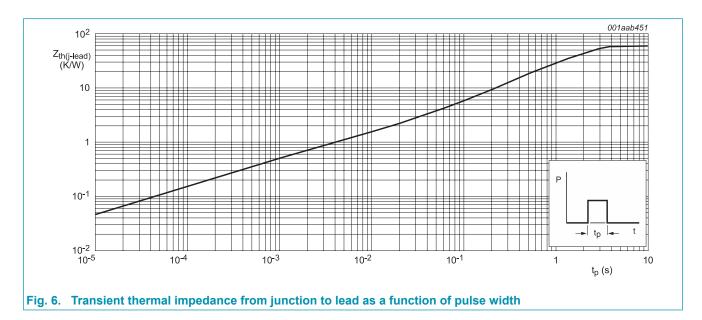


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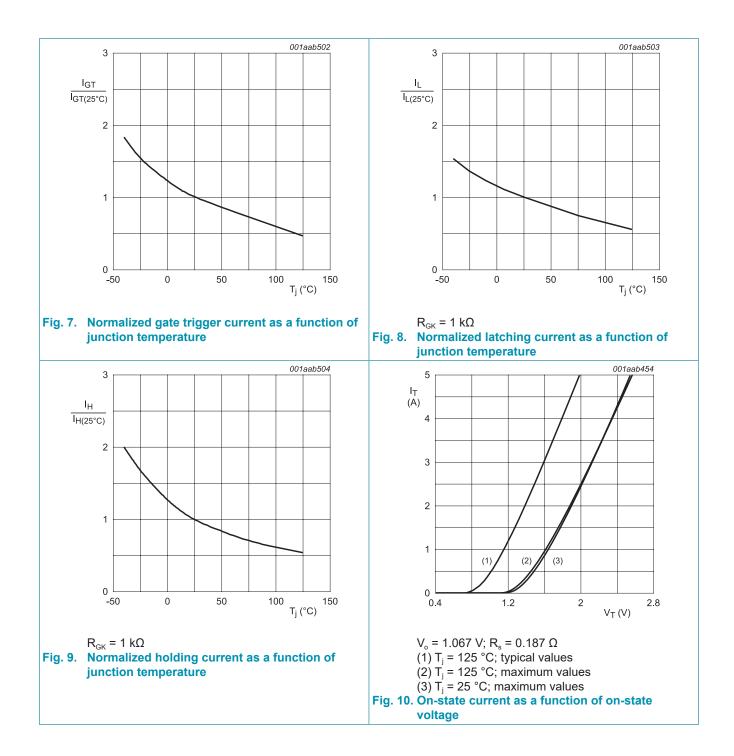
9. Thermal characteristics

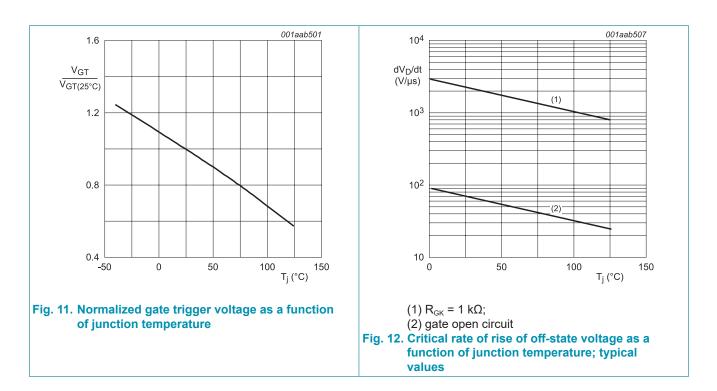
able 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	<u>Fig. 6</u>		-	-	60	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	printed circuit board mounted: lead length = 4 mm		-	150	-	K/W



10. Characteristics

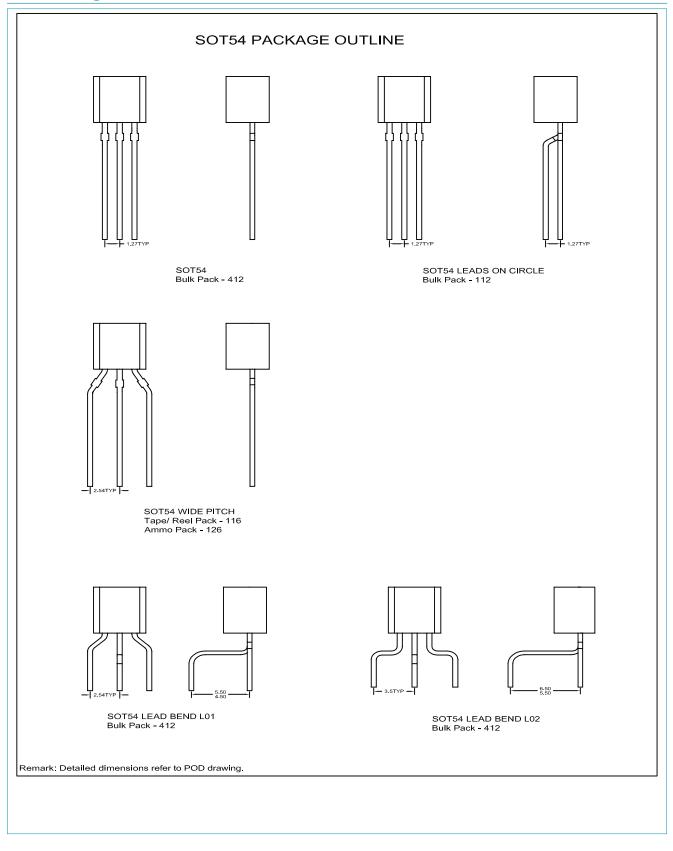
Table 7. Cl	naracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>	-	50	200	μA
I _L	latching current	V_{D} = 12 V; I _G = 0.5 mA; T _j = 25 °C; R _{GK(ext)} = 1 kΩ; Fig. 8	-	2	6	mA
I _H	holding current	V_D = 12 V; T _j = 25 °C; R _{GK(ext)} = 1 kΩ; Fig. 9	-	2	5	mA
V _T	on-state voltage	I _T = 1.2 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 11	-	0.5	0.8	V
		V _D = 200 V; I _T = 10 mA; T _j = 125 °C	0.2	0.3	-	V
I _D	off-state current	$V_{\rm D}$ = 200 V; $R_{\rm GK(ext)}$ = 1 kΩ; $T_{\rm j}$ = 125 °C	-	0.05	0.1	mA
I _R	reverse current	V_{R} = 200 V; T _j = 125 °C; R _{GK(ext)} = 1 kΩ	-	0.05	0.1	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 134 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12	500	800	-	V/µs
		V_{DM} = 134 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	-	25	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 2 \text{ A}; V_{\text{D}} = 200 \text{V}; I_{\text{G}} = 10 \text{mA}; \text{d} I_{\text{G}} \text{/} \\ \text{d} t = 0.1 \text{A} / \mu \text{s}; T_{\text{j}} = 25 ^{\circ}\text{C}$	-	2	-	μs
t _q	commutated turn-off time		-	100	-	μs

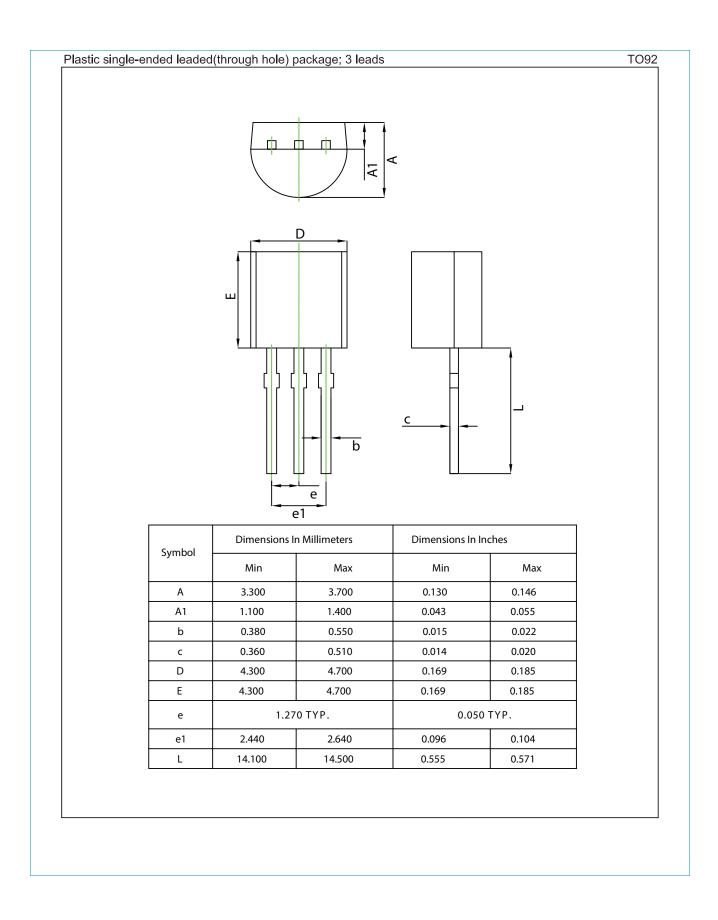




SCR

11. Package outline





12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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